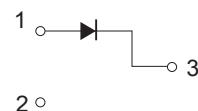




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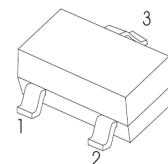


RB400D SCHOTTKY BARRIER DIODE

FEATURES

- Small surface mounting type
- Low reverse current and low forward voltage
- High reliability

MARKING: D3A



SOT-23

Maximum Ratings @Ta=25°C

| Parameter | Symbol | Limit | Unit |
|--|------------------|----------|------|
| Peak reverse voltage | V _{RM} | 40 | V |
| DC reverse | V _R | 40 | V |
| Non-repetitive Peak Forward Surge Current @t=8.3ms | I _{FSM} | 3 | A |
| Mean rectifying current | I _o | 0.5 | A |
| Power dissipation | P _D | 250 | mW |
| Thermal resistance from junction to ambient | R _{θJA} | 400 | °C/W |
| Junction temperature | T _j | 125 | °C |
| Storage temperature | T _{stg} | -55~+150 | °C |

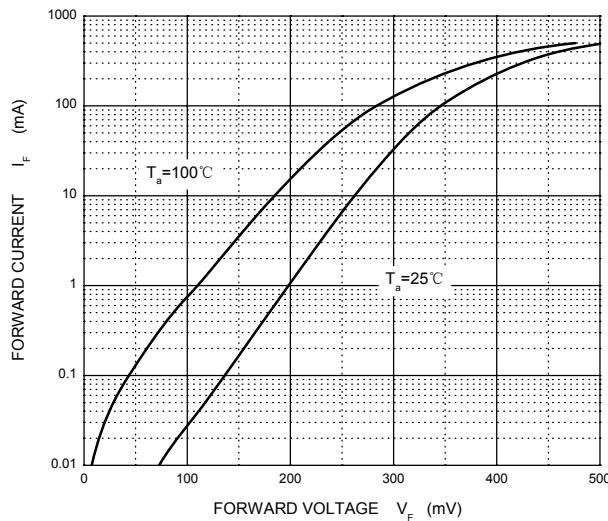
Electrical Ratings (Ta=25°C unless otherwise specified)

| Parameter | Symbol | Min | Typ | Max | Unit | Conditions |
|-------------------------------|-----------------|-----|-----|------|------|----------------------------|
| Reverse breakdown voltage | V _R | 40 | | | V | I _R =100μA |
| Forward voltage | V _F | | | 0.55 | V | I _F =0.5A |
| Reverse current | I _{R1} | | | 50 | μA | V _R =30V |
| | I _{R2} | | | 30 | μA | V _R =10V |
| Capacitance between terminals | C _{T1} | | 125 | | pF | V _R =0V,f=1MHz |
| | C _{T2} | | 20 | | pF | V _R =10V,f=1MHz |

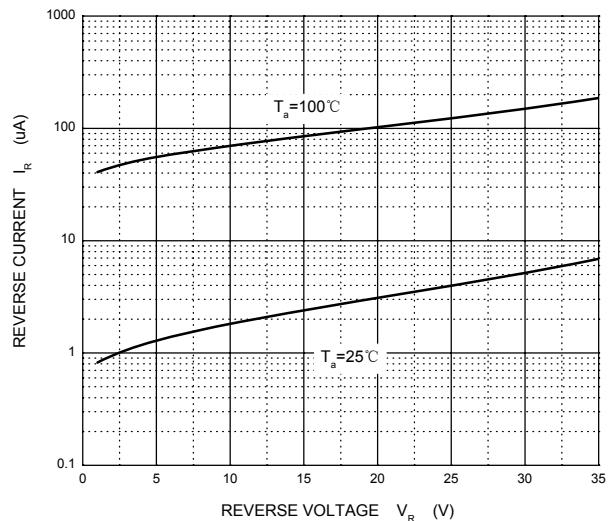


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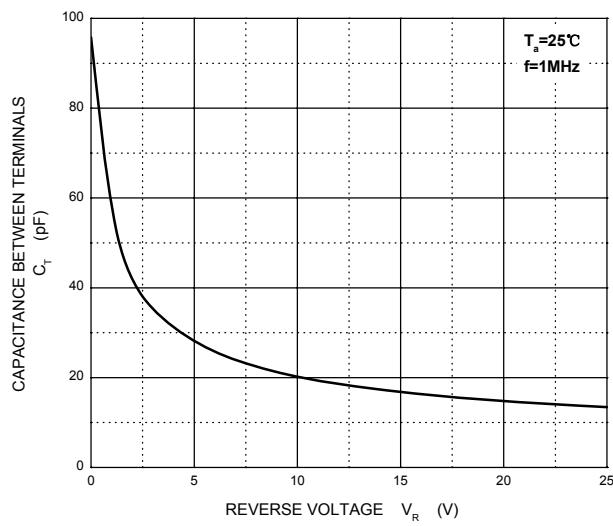
Forward Characteristics



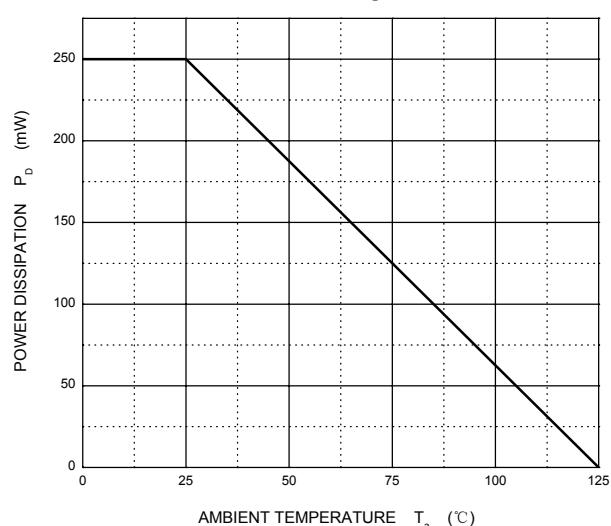
Reverse Characteristics



Capacitance Characteristics



Power Derating Curve



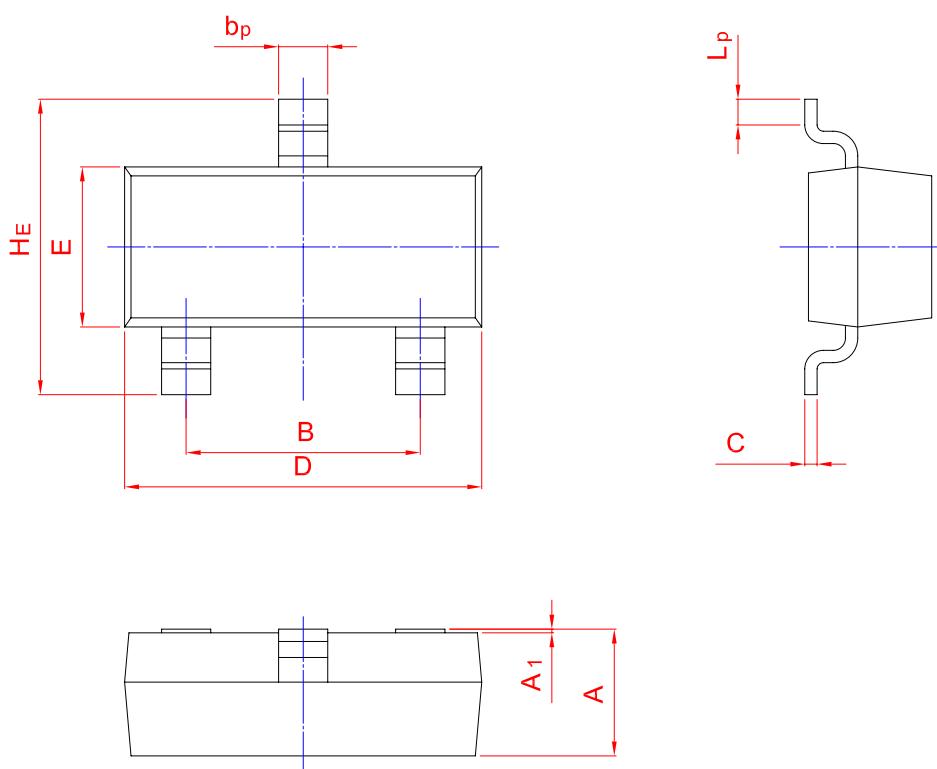


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PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



| UNIT | A | B | b _p | C | D | E | H _E | A ₁ | L _p |
|------|--------------|--------------|----------------|--------------|--------------|--------------|----------------|----------------|----------------|
| mm | 1.40 0.95 | 2.04 1.78 | 0.50 0.35 | 0.19 0.08 | 3.10 2.70 | 1.65 1.20 | 3.00 2.20 | 0.100 0.013 | 0.50 0.20 |